# Voltage Regulator - Ultra **High Accuracy, Low Iq, Low Dropout, Enable**

# 500 mA

The NCV8535 is a high performance, low dropout regulator. With accuracy of ±0.9% over line and load and ultra-low quiescent current and noise it encompasses all of the necessary features required by today's consumer electronics. This unique device is guaranteed to be stable without a minimum load current requirement and stable with any type of capacitor as small as 1.0 µF. The NCV8535 also comes equipped with sense and noise reduction pins to increase the overall utility of the device. The NCV8535 offers reverse bias protection.

# Features

- High Accuracy Over Line and Load (±0.9% at 25°C)
- Ultra-Low Dropout Voltage at Full Load (260 mV typ.)
- No Minimum Output Current Required for Stability
- Low Noise (31 µVrms w/10 nF Cnr and 51 µVrms w/out Cnr)
- Low Shutdown Current (0.07 μA)
- Reverse Bias Protected
- 2.9 V to 12 V Supply Range
- Thermal Shutdown Protection
- Current Limitation
- Requires Only 1.0 µF Output Capacitance for Stability
- Stable with Any Type of Capacitor (including MLCC)
- Available in 1.5 V, 1.8 V, 1.9 V, 2.5 V, 2.8 V, 2.85 V, 3.0 V, 3.3 V, 3.5 V, 5.0 V and Adjustable Output Voltages
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free Devices

# Applications

- PCMCIA Card
- Cellular Phones
- Camcoders and Cameras
- Networking Systems, DSL/Cable Modems
- Cable Set-Top Box
- MP3/CD Players
- DSP Supply
- Displays and Monitors



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DFN10 CASE 485C

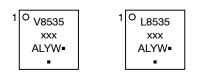


# CASE 507AM

## **PIN CONFIGURATION**

Fixed Version	Adj Version
Pin 1, 2. V <sub>out</sub>	Pin 1, 2. V <sub>out</sub>
<ol><li>Sense</li></ol>	3. Adj
4. GND	4. GND
5, 6. NC	5, 6. NC
7. NR	7. NR
8. <u>SD</u>	8. <u>SD</u>
9, 10. V <sub>in</sub>	9, 10. V <sub>in</sub>

# MARKING DIAGRAM



V8535 = Specific Device Code

- L8535 = Specific Device Code
- = ADJ, 150, 180, 190, 250, 280, XXX 285, 300, 330, 350, 500
- Α = Assembly Location
- 1 = Wafer Lot
- Y = Year
- = Work Week W
  - = Pb-Free Package

(Note: Microdot may be in either location)

# **ORDERING INFORMATION**

See detailed ordering, marking and shipping information in the package dimensions section on page 21 of this data sheet.

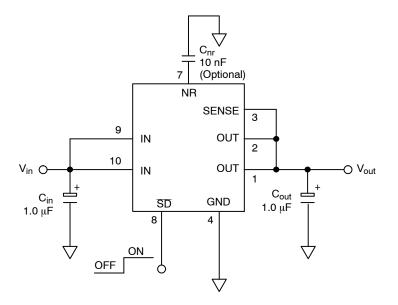


Figure 1. Typical Fixed Version Application Schematic

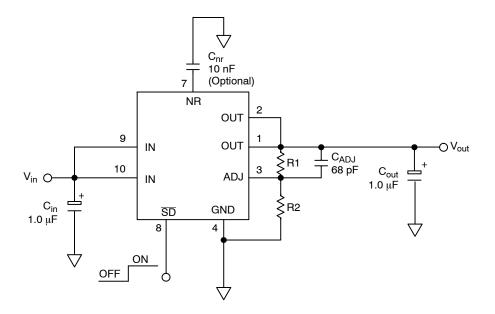


Figure 2. Typical Adjustable Version Application Schematic

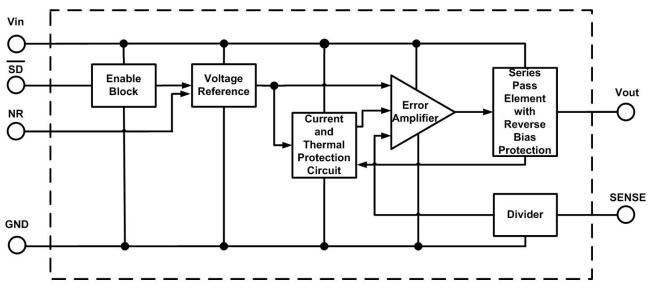


Figure 3. Block Diagram, Fixed Output Version

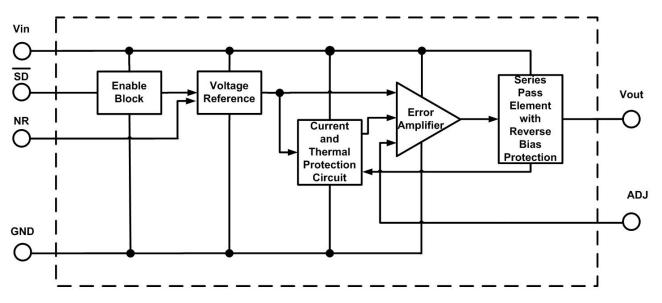


Figure 4. Block Diagram, Adjustable Output Version

## PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Description
FIXED VER	SION	
1, 2	V <sub>out</sub>	Regulated output voltage. Bypass to ground with $C_{out} \ge 1.0 \ \mu\text{F}.$
3	SENSE	For output voltage sensing, connect to Pins 1 and 2.
4	GND	Power Supply Ground
7	NR	Noise Reduction Pin. This is an optional pin used to further reduce noise.
8	SD	Shutdown pin. When not in use, this pin should be connected to the input pin.
9, 10	V <sub>in</sub>	Power Supply Input Voltage
5, 6	NC	Not Connected
EPAD	EPAD	Exposed thermal pad should be connected to ground.

# ADJUSTABLE VERSION

1, 2	Vout	Regulated output voltage. Bypass to ground with $C_{out} \ge 1.0 \ \mu\text{F}.$
3	Adj	Adjustable pin; reference voltage = 1.25 V.
4	GND	Power Supply Ground
7	NR	Noise Reduction Pin. This is an optional pin used to further reduce noise.
8	SD	Shutdown pin. When not in use, this pin should be connected to the input pin.
9, 10	V <sub>in</sub>	Power Supply Input Voltage
5, 6	NC	Not Connected
EPAD	EPAD	Exposed thermal pad should be connected to ground.

#### **MAXIMUM RATINGS**

Rating	Symbol	/mbol Value		
Input Voltage	V <sub>in</sub> -0.3 to +16			
Output Voltage	V <sub>out</sub> –0.3 to V <sub>in</sub> +0.3 or 10 V*			
Shutdown Pin Voltage	V <sub>sh</sub>	/ <sub>sh</sub> –0.3 to +16		
Junction Temperature Range	Т <sub>Ј</sub>	–40 to +150	°C	
Storage Temperature Range	T <sub>stg</sub>	–55 to +150	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

should not be assumed, damage may occur and reliability may be affected. NOTE: This device series contains ESD protection and exceeds the following tests: Human Body Model (HBM) tested per AEC-Q100-002 (EIA/JESD22-A114)

Machine Model (MM) tested per AEC-Q100-003 (EIA/JESD22-A115)

Charged Device Model (CDM) tested per EIA/JESD22-C101

\*Which ever is less. Reverse bias protection feature valid only if  $V_{out} - V_{in} \le 7 \text{ V}$ .

#### THERMAL CHARACTERISTICS

	Test Conditions	(Typical Value)	
Characteristic	Min Pad Board (Note 1)	1" Pad Board (Note 1)	Unit
Junction-to-Air, θJA	215	66	°C/W
Junction-to-Pin, ψJL2	55	17	°C/W

1. As mounted on a 35 x 35 x 1.5 mm FR4 Substrate, with a single layer of a specified copper area of 2 oz (0.07 mm thick) copper traces and heat spreading area. JEDEC 51 specifications for a low and high conductivity test board recommend a 2 oz copper thickness. Test conditions are under natural convection or zero air flow.

## **ELECTRICAL CHARACTERISTICS - 5.0 V**

(V<sub>out</sub> = 5.0 V typical, V<sub>in</sub> = 5.4 V,  $T_A$  = -40°C to +85°C, unless otherwise noted, Note 2.)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) V <sub>in</sub> = 5.4 V to 9.0 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 25°C	V <sub>out</sub>	-0.9% 4.955	5.0	+0.9% 5.045	V
Output Voltage (Accuracy) $V_{in} = 5.4 \text{ V to } 9.0 \text{ V}, I_{load} = 0.1 \text{ mA to } 500 \text{ mA}, T_A = 0^{\circ}\text{C to } +85^{\circ}\text{C}$	V <sub>out</sub>	-1.4% 4.930	5.0	+1.4% 5.070	V
Output Voltage (Accuracy) $V_{in} = 5.4 \text{ V to } 9.0 \text{ V}, \text{ I}_{load} = 0.1 \text{ mA to } 500 \text{ mA}, \text{ T}_{\text{A}} = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}$	V <sub>out</sub>	-1.5% 4.925	5.0	+1.5% 5.075	V
Line Regulation V <sub>in</sub> = 5.4 V to 12 V, I <sub>load</sub> = 0.1 mA	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation V <sub>in</sub> = 5.4 V, I <sub>load</sub> = 0.1 mA to 500 mA	Load <sub>Reg</sub>		0.04		mV/mA
Dropout Voltage (See App Note) I <sub>load</sub> = 500 mA I <sub>load</sub> = 300 mA I <sub>load</sub> = 50 mA I <sub>load</sub> = 0.1 mA	V <sub>DO</sub>			340 230 110 10	mV
Peak Output Current (See Figure 16)	lpk	500	700	830	mA
Short Output Current (See Figure 16)	I <sub>sc</sub>			930	mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation I <sub>load</sub> = 500 mA (Note 3) I <sub>load</sub> = 300 mA (Note 3) I <sub>load</sub> = 50 mA I <sub>load</sub> = 0.1 mA	I <sub>GND</sub>		9.0 4.6 0.8 -	14 7.5 2.5 190	mA μA
In Dropout V <sub>in</sub> = 4.9 V, I <sub>load</sub> = 0.1 mA			-	500	μΑ
In Shutdown S <sub>D</sub> = 0 V	I <sub>GNDsh</sub>		0.07	1.0	μA
Output Noise $C_{nr} = 0 nF, I_{load} = 500 mA, f = 10 Hz to 100 kHz, C_{out} = 10 \mu F$ $C_{nr} = 10 nF, I_{load} = 500 mA, f = 10 Hz to 100 kHz, C_{out} = 10 \mu F$	V <sub>noise</sub>		93 58		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	V V
$S_{D}$ Input Current, $V_{SD}$ = 0 V to 0.4 V or $V_{SD}$ = 2.0 V to $V_{in}$	I <sub>SD</sub>		0.07	1.0	μA
Output Current In Shutdown Mode, V <sub>out</sub> = 0 V	I <sub>OSD</sub>		0.07	1.0	μA
Reverse Bias Protection, Current Flowing from the Output Pin to GND $(V_{in} = 0 \text{ V}, V_{out forced} = 5.0 \text{ V})$	I <sub>OUTR</sub>		10		μA

Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
 T<sub>A</sub> must be greater than 0°C.

## **ELECTRICAL CHARACTERISTICS - 3.5 V**

(V<sub>out</sub> = 3.5 V typical, V<sub>in</sub> = 3.9 V,  $T_A$  = -40°C to +85°C, unless otherwise noted, Note 4.)

V <sub>out</sub>	-0.9% 3.469	3.5	+0.9%	V
V <sub>out</sub>			3.532	v
	-1.4% 3.451	3.5	+1.4% 3.549	V
V <sub>out</sub>	-1.5% 3.448	3.5	+1.5% 3.553	V
Line <sub>Reg</sub>		0.04		mV/V
Load <sub>Reg</sub>		0.04		mV/mA
V <sub>DO</sub>			340 230 110 10	mV
lpk	500	700	800	mA
I <sub>sc</sub>			900	mA
TJ		160		°C
I <sub>GND</sub>		9.0 4.6 0.8 -	14 7.5 2.5 190	mA μA
		-	500	μΑ
I <sub>GNDsh</sub>		0.07	1.0	μA
V <sub>noise</sub>		68 47		μVrms μVrms
	2.0		0.4	V V
I <sub>SD</sub>		0.07	1.0	μA
I <sub>OSD</sub>		0.07	1.0	μA
IOUTR		10		μA
	Line <sub>Reg</sub> Load <sub>Reg</sub> V <sub>DO</sub> Ipk Isc TJ IGND IGNDsh Vnoise Vnoise ISD	3.448       Line <sub>Reg</sub> Load <sub>Reg</sub> VDO       VDO       Ipk       Jpk       Jpk <td< td=""><td>3.448         Line<sub>Reg</sub>       0.04         Load<sub>Reg</sub>       0.04         V<sub>DO</sub>       0.04         V<sub>DO</sub>       100         Ipk       500       700         IgND       9.0       4.6         IGND       9.0       4.6         IGND       0.07       4.6         Vnoise       68       -         IGNDsh       0.07       68         Isp       2.0       0.07         IoSp       0.07       0.07</td><td>3.448       3.553         Line<sub>Reg</sub>       0.04         Load<sub>Reg</sub>       0.04         VDO       0.04         VDO       340         Ipk       500         Ipk       500         Ipk       500         Ipk       900         Ipk       500         Ipk       160         Ipk       160         Ipk       160         Ipk       10         Ipk       10         Ipk       10         Ipk       10         Ipk       10         Ipk       2.0         Ipk       1.0         Ipk       2.0         Ipk       0.07         Ipk&lt;</td></td<>	3.448         Line <sub>Reg</sub> 0.04         Load <sub>Reg</sub> 0.04         V <sub>DO</sub> 0.04         V <sub>DO</sub> 100         Ipk       500       700         IgND       9.0       4.6         IGND       9.0       4.6         IGND       0.07       4.6         Vnoise       68       -         IGNDsh       0.07       68         Isp       2.0       0.07         IoSp       0.07       0.07	3.448       3.553         Line <sub>Reg</sub> 0.04         Load <sub>Reg</sub> 0.04         VDO       0.04         VDO       340         Ipk       500         Ipk       500         Ipk       500         Ipk       900         Ipk       500         Ipk       160         Ipk       160         Ipk       160         Ipk       10         Ipk       10         Ipk       10         Ipk       10         Ipk       10         Ipk       2.0         Ipk       1.0         Ipk       2.0         Ipk       0.07         Ipk<

Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
 T<sub>A</sub> must be greater than 0°C.

## **ELECTRICAL CHARACTERISTICS - 3.3 V**

(V<sub>out</sub> = 3.3 V typical, V<sub>in</sub> = 3.7 V,  $T_A$  = -40°C to +85°C, unless otherwise noted, Note 6.)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) V <sub>in</sub> = 3.7 V to 7.3 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 25°C	V <sub>out</sub>	-0.9% 3.270	3.3	+0.9% 3.330	V
Output Voltage (Accuracy) $V_{in}$ = 3.7 V to 7.3 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 0°C to +85°C	V <sub>out</sub>	-1.4% 3.254	3.3	+1.4% 3.346	V
Output Voltage (Accuracy) $V_{in}$ = 3.7 V to 7.3 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = -40°C to +125°C	V <sub>out</sub>	-1.5% 3.250	3.3	+1.5% 3.350	V
Line Regulation V <sub>in</sub> = 3.7 V to 12 V, I <sub>load</sub> = 0.1 mA	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation V <sub>in</sub> = 3.7 V, I <sub>load</sub> = 0.1 mA to 500 mA	Load <sub>Reg</sub>		0.04		mV/mA
Dropout Voltage (See App Note) $I_{load} = 500 \text{ mA}$ $I_{load} = 300 \text{ mA}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$	V <sub>DO</sub>			340 230 110 10	mV
Peak Output Current (See Figure 16)	lpk	500	700	800	mA
Short Output Current (See Figure 16)	I <sub>sc</sub>			900	mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation $I_{load} = 500 \text{ mA}$ (Note 7) $I_{load} = 300 \text{ mA}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$	I <sub>GND</sub>		9.0 4.6 0.8 -	14 7.5 2.5 190	mA μA
In Dropout V <sub>in</sub> = 3.2 V, I <sub>load</sub> = 0.1 mA			-	500	μΑ
In Shutdown S <sub>D</sub> = 0 V	I <sub>GNDsh</sub>		0.07	1.0	μA
Output Noise $C_{nr} = 0 nF, I_{load} = 500 mA, f = 10 Hz to 100 kHz, Cout = 10 \muFC_{nr} = 10 nF, I_{load} = 500 mA, f = 10 Hz to 100 kHz, Cout = 10 \muF$	V <sub>noise</sub>		69 46		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	v v
$S_{D}$ Input Current, $V_{SD}$ = 0 V to 0.4 V or $V_{SD}$ = 2.0 V to $V_{in}$	I <sub>SD</sub>		0.07	1.0	μΑ
Output Current In Shutdown Mode, V <sub>out</sub> = 0 V	I <sub>OSD</sub>		0.07	1.0	μΑ
Reverse Bias Protection, Current Flowing from the Output Pin to GND $(V_{in} = 0 \text{ V}, V_{out forced} = 3.3 \text{ V})$	I <sub>OUTR</sub>		10		μΑ

6. Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
 7. T<sub>A</sub> must be greater than 0°C.

## **ELECTRICAL CHARACTERISTICS - 3.0 V**

(V<sub>out</sub> = 3.0 V typical, V<sub>in</sub> = 3.4 V,  $T_A$  = -40°C to +85°C, unless otherwise noted, Note 8.)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) V <sub>in</sub> = 3.4 V to 7.0 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 25°C	V <sub>out</sub>	-0.9% 2.973	3.0	+0.9% 3.027	V
Output Voltage (Accuracy) $V_{in}$ = 3.4 V to 7.0 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 0°C to +85°C	V <sub>out</sub>	-1.4% 2.958	3.0	+1.4% 3.042	V
Output Voltage (Accuracy) $V_{in}$ = 3.4 V to 7.0 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = -40°C to +125°C	V <sub>out</sub>	-1.5% 2.955	3.0	+1.5% 3.045	V
Line Regulation V <sub>in</sub> = 3.4 V to 12 V, I <sub>load</sub> = 0.1 mA	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation V <sub>in</sub> = 3.4 V, I <sub>load</sub> = 0.1 mA to 500 mA	Load <sub>Reg</sub>		0.04		mV/mA
Dropout Voltage (See App Note) $I_{load} = 500 \text{ mA}$ $I_{load} = 300 \text{ mA}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$	V <sub>DO</sub>			340 230 110 10	mV
Peak Output Current (See Figure 16)	lpk	500	700	800	mA
Short Output Current (See Figure 16)	I <sub>sc</sub>			900	mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation I <sub>load</sub> = 500 mA (Note 9) I <sub>load</sub> = 300 mA I <sub>load</sub> = 50 mA I <sub>load</sub> = 0.1 mA	I <sub>GND</sub>		9.0 4.6 0.8	14 7.5 2.5 190	mA μA
In Dropout V <sub>in</sub> = 2.9 V, I <sub>load</sub> = 0.1 mA			-	500	μΑ
In Shutdown S <sub>D</sub> = 0 V	I <sub>GNDsh</sub>		0.07	1.0	μA
Output Noise $C_{nr} = 0 \text{ nF}, I_{load} = 500 \text{ mA}, f = 10 \text{ Hz to } 100 \text{ kHz}, C_{out} = 10 \mu\text{F}$ $C_{nr} = 10 \text{ nF}, I_{load} = 500 \text{ mA}, f = 10 \text{ Hz to } 100 \text{ kHz}, C_{out} = 10 \mu\text{F}$	V <sub>noise</sub>		56 37		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	v v
$S_{D}$ Input Current, $V_{SD}$ = 0 V to 0.4 V or $V_{SD}$ = 2.0 V to $V_{in}$	I <sub>SD</sub>		0.07	1.0	μΑ
Output Current In Shutdown Mode, V <sub>out</sub> = 0 V	I <sub>OSD</sub>		0.07	1.0	μΑ
Reverse Bias Protection, Current Flowing from the Output Pin to GND $(V_{in} = 0 \text{ V}, V_{out forced} = 3.0 \text{ V})$	IOUTR		10		μΑ

Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
 T<sub>A</sub> must be greater than 0°C.

#### **ELECTRICAL CHARACTERISTICS - 2.85 V**

(V<sub>out</sub> = 2.85 V typical, V<sub>in</sub> = 3.25 V, T<sub>A</sub> =  $-40^{\circ}$ C to  $+85^{\circ}$ C, unless otherwise noted, Note 10)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) $V_{in}$ = 3.25 V to 6.85 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 25°C	V <sub>out</sub>	-0.9% 2.824	2.85	+0.9% 2.876	V
Output Voltage (Accuracy) V <sub>in</sub> = 3.25 V to 6.85 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 0°C to +85°C	V <sub>out</sub>	-1.4% 2.810	2.85	+1.4% 2.890	V
Output Voltage (Accuracy) (Note 11) $V_{in}$ = 3.25 V to 6.85 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = -40°C to +125°C	V <sub>out</sub>	-1.5% 2.807	2.85	+1.5% 2.893	V
Line Regulation V <sub>in</sub> = 3.25 V to 12 V, I <sub>load</sub> = 0.1 mA	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation V <sub>in</sub> = 3.25 V, I <sub>load</sub> = 0.1 mA to 500 mA	Load <sub>Reg</sub>		0.04		mV/mA
Dropout Voltage (See App Note) $I_{load} = 500 \text{ mA}$ $I_{load} = 300 \text{ mA}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1\text{mA}$	V <sub>DO</sub>			340 230 110 10	mV
Peak Output Current (See Figure 16)	I <sub>pk</sub>	500	700	800	mA
Short Output Current (See Figure 16)	I <sub>sc</sub>			900	mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation $I_{load} = 500 \text{ mA} \text{ (Note 12)}$ $I_{load} = 300 \text{ mA}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$	I <sub>GND</sub>		9.0 4.6 0.8 -	14 7.5 2.5 190	mA μA
In Dropout V <sub>in</sub> = 2.75 V, I <sub>load</sub> = 0.1 mA			_	500	μΑ
In Shutdown S <sub>D</sub> = 0 V	I <sub>GNDsh</sub>		0.07	1.0	μA
Output Noise $C_{nr} = 0 \text{ nF}$ , $I_{load} = 500 \text{ mA}$ , f = 10 Hz to 100 kHz, $C_{out} = 10 \mu\text{F}$ $C_{nr} = 10 \text{ nF}$ , $I_{load} = 500 \text{ mA}$ , f = 10 Hz to 100 kHz, $C_{out} = 10 \mu\text{F}$	V <sub>noise</sub>		61 40		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	V V
$S_D$ Input Current, $V_{SD}$ = 0 V to 0.4 V or $V_{SD}$ = 2.0 V to $V_{in}$	I <sub>SD</sub>		0.07	1.0	μA
Output Current In Shutdown Mode, V <sub>out</sub> = 0 V	I <sub>OSD</sub>		0.07	1.0	μΑ
Reverse Bias Protection, Current Flowing from the Output Pin to GND (V <sub>in</sub> = 0 V, V <sub>out forced</sub> = 2.85 V)	IOUTR		10		μA

10. Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
11. For output current capability for T<sub>A</sub> < 0°C, please refer to Figure 18.</li>
12. T<sub>A</sub> must be greater than 0°C.

#### **ELECTRICAL CHARACTERISTICS - 2.8 V**

(V<sub>out</sub> = 2.8 V typical, V<sub>in</sub> = 3.2 V,  $T_A$  = -40°C to +85°C, unless otherwise noted, Note 13.)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) V <sub>in</sub> = 3.2 V to 6.8 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 25°C	V <sub>out</sub>	-0.9% 2.774	2.8	+0.9% 2.826	V
Output Voltage (Accuracy) $V_{in} = 3.2 \text{ V to } 6.8 \text{ V}, I_{load} = 0.1 \text{ mA to } 500 \text{ mA}, T_A = 0^{\circ}\text{C to } +85^{\circ}\text{C}$	V <sub>out</sub>	-1.4% 2.760	2.8	+1.4% 2.840	V
Output Voltage (Accuracy) (Note 14) $V_{in} = 3.2$ V to 6.8 V, $I_{load} = 0.1$ mA to 500 mA, $T_A = -40^{\circ}$ C to +125°C	V <sub>out</sub>	-1.5% 2.758	2.8	+1.5% 2.842	V
Line Regulation V <sub>in</sub> = 3.2 V to 12 V, I <sub>load</sub> = 0.1 mA	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation V <sub>in</sub> = 3.2 V, I <sub>load</sub> = 0.1 mA to 500 mA	Load <sub>Reg</sub>		0.04		mV/mA
Dropout Voltage (See App Note) $I_{load} = 500 \text{ mA}$ $I_{load} = 300 \text{ mA}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1\text{mA}$	V <sub>DO</sub>			340 230 110 10	mV
Peak Output Current (See Figure 16)	I <sub>pk</sub>	500	700	800	mA
Short Output Current (See Figure 16)	l <sub>sc</sub>			900	mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation $I_{load} = 500$ mA (Note 15) $I_{load} = 300$ mA (Note 15) $I_{load} = 50$ mA $I_{load} = 0.1$ mA	I <sub>GND</sub>		9.0 4.6 0.8 -	14 7.5 2.5 190	mA μA
In Dropout V <sub>in</sub> = 2.7 V, I <sub>load</sub> = 0.1 mA			_	500	μΑ
In Shutdown S <sub>D</sub> = 0 V	I <sub>GNDsh</sub>		0.07	1.0	μA
Output Noise $C_{nr} = 0 \text{ nF}$ , $I_{load} = 500 \text{ mA}$ , f = 10 Hz to 100 kHz, $C_{out} = 10 \mu F$ $C_{nr} = 10 \text{ nF}$ , $I_{load} = 500 \text{ mA}$ , f = 10 Hz to 100 kHz, $C_{out} = 10 \mu F$	V <sub>noise</sub>		52 36		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	v v
$S_{D}$ Input Current, $V_{SD}$ = 0 V to 0.4 V or $V_{SD}$ = 2.0 V to $V_{in}$	I <sub>SD</sub>		0.07	1.0	μA
Output Current In Shutdown Mode, V <sub>out</sub> = 0 V	I <sub>OSD</sub>		0.07	1.0	μA
Reverse Bias Protection, Current Flowing from the Output Pin to GND (V <sub>in</sub> = 0 V, V <sub>out_forced</sub> = 2.8 V)	I <sub>OUTR</sub>		10		μΑ

13. Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
14. For output current capability for T<sub>A</sub> < 0°C, please refer to Figure 19.</li>
15. T<sub>A</sub> must be greater than 0°C.

#### **ELECTRICAL CHARACTERISTICS - 2.5 V**

(V<sub>out</sub> = 2.5 V typical, V<sub>in</sub> = 2.9 V,  $T_A$  = -40°C to +85°C, unless otherwise noted, Note 16.)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) V <sub>in</sub> = 2.9 V to 6.5 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 25°C	V <sub>out</sub>	-0.9% 2.477	2.5	+0.9% 2.523	V
Output Voltage (Accuracy) V <sub>in</sub> = 2.9 V to 6.5 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 0°C to +85°C	V <sub>out</sub>	-1.4% 2.465	2.5	+1.4% 2.535	V
Output Voltage (Accuracy), (Note 17) $V_{in} = 2.9 V$ to 6.5 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = -40°C to +125°C	V <sub>out</sub>	-1.5% 2.462	2.5	+1.5% 2.538	V
Line Regulation V <sub>in</sub> = 2.9 V to 12 V, I <sub>load</sub> = 0.1 mA	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation V <sub>in</sub> = 2.9 V, I <sub>load</sub> = 0.1 mA to 500 mA	Load <sub>Reg</sub>		0.04		mV/mA
Dropout Voltage (See App Note) I <sub>load</sub> = 500 mA (Note 18) I <sub>load</sub> = 300 mA (Note 18) I <sub>load</sub> = 50 mA I <sub>load</sub> = 0.1mA	V <sub>DO</sub>			340 230 110 10	mV
Peak Output Current (See Figure 16)	I <sub>pk</sub>	500	700	800	mA
Short Output Current (See Figure 16)	I <sub>sc</sub>			900	mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation I <sub>load</sub> = 500 mA (Note 18) I <sub>load</sub> = 300 mA (Note 18) I <sub>load</sub> = 50 mA I <sub>load</sub> = 0.1 mA	I <sub>GND</sub>		9.0 4.6 0.8 -	14 7.5 2.5 190	mA μA
In Dropout V <sub>in</sub> = 2.4 V, I <sub>load</sub> = 0.1 mA				500	μΑ
In Shutdown S <sub>D</sub> = 0 V	I <sub>GNDsh</sub>		0.07	1.0	μA
Output Noise $C_{nr} = 0 \text{ nF}, I_{load} = 500 \text{ mA}, f = 10 \text{ Hz to } 100 \text{ kHz}, C_{out} = 10 \mu\text{F}$ $C_{nr} = 10 \text{ nF}, I_{load} = 500 \text{ mA}, f = 10 \text{ Hz to } 100 \text{ kHz}, C_{out} = 10 \mu\text{F}$	V <sub>noise</sub>		56 35		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	V V
$S_{D}$ Input Current, $V_{SD}$ = 0 V to 0.4 V or $V_{SD}$ = 2.0 V to $V_{in}$	I <sub>SD</sub>		0.07	1.0	μA
Output Current In Shutdown Mode, V <sub>out</sub> = 0 V	I <sub>OSD</sub>		0.07	1.0	μA
Reverse Bias Protection, Current Flowing from the Output Pin to GND (V <sub>in</sub> = 0 V, V <sub>out forced</sub> = 2.5 V)	I <sub>OUTR</sub>		10		μΑ

16. Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
17. For output current capability for T<sub>A</sub> < 0°C, please refer to Figure 20.</li>
18. T<sub>A</sub> must be greater than 0°C.

## **ELECTRICAL CHARACTERISTICS - 1.9 V**

(V<sub>out</sub> = 1.9 V typical, V<sub>in</sub> = 2.9 V,  $T_A = -40^{\circ}C$  to +85°C, unless otherwise noted, Note 19.)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) V <sub>in</sub> = 2.9 V to 5.9 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 25°C	V <sub>out</sub>	-0.9% 1.883	1.9	+0.9% 1.917	V
Output Voltage (Accuracy) $V_{in} = 2.9 V$ to 5.9 V, $I_{load} = 0.1 mA$ to 500 mA, $T_A = 0^{\circ}C$ to +85°C	V <sub>out</sub>	-1.4% 1.873	1.9	+1.4% 1.927	V
Output Voltage (Accuracy), (Note 20) $V_{in}$ = 2.9 V to 5.9 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = -40°C to +125°C	V <sub>out</sub>	-1.5% 1.872	1.9	+1.5% 1.929	V
Line Regulation V <sub>in</sub> = 2.9 V to 12 V, I <sub>load</sub> = 0.1 mA	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation V <sub>in</sub> = 2.9 V, I <sub>load</sub> = 0.1 mA to 500 mA	Load <sub>Reg</sub>		0.04		mV/mA
Dropout Voltage (See App Note) I <sub>load</sub> = 500 mA (Notes 21, 22) I <sub>load</sub> = 300 mA (Notes 21, 22) I <sub>load</sub> = 50 mA (Notes 21, 22)	V <sub>DO</sub>		367 156 90	1030 1030 1030	mV
Peak Output Current (See Figure 16)	I <sub>pk</sub>	500	700	800	mA
Short Output Current (See Figure 16)	I <sub>sc</sub>			900	mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation I <sub>load</sub> = 500 mA (Note 21) I <sub>load</sub> = 300 mA (Note 21) I <sub>load</sub> = 50 mA I <sub>load</sub> = 0.1 mA	I <sub>GND</sub>		9.0 4.6 0.8 -	14 7.5 2.5 190	mA μA
In Dropout $V_{in} = 2.2 \text{ V}, \text{ I}_{load} = 0.1 \text{ mA}$				500	μΑ
In Shutdown $S_D = 0 V$	I <sub>GNDsh</sub>		0.07	1.0	μΑ
Output Noise C <sub>nr</sub> = 0 nF, I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF C <sub>nr</sub> = 10 nF, I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF	V <sub>noise</sub>		53 33		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	V V
$S_D$ Input Current, $V_{SD}$ = 0 V to 0.4 V or $V_{SD}$ = 2.0 V to $V_{in}$	I <sub>SD</sub>		0.07	1.0	μA
Output Current In Shutdown Mode, V <sub>out</sub> = 0 V	I <sub>OSD</sub>		0.07	1.0	μA
Reverse Bias Protection, Current Flowing from the Output Pin to GND (V <sub>in</sub> = 0 V, V <sub>out forced</sub> = 1.9 V)	I <sub>OUTR</sub>		10		μΑ

19. Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
20. For output current capability for T<sub>A</sub> < 0°C, please refer to Figure 21.</li>
21. T<sub>A</sub> must be greater than 0°C.
22. Maximum dropout voltage is limited by minimum input voltage V<sub>in</sub> = 2.9 V recommended for guaranteed operation.

## **ELECTRICAL CHARACTERISTICS - 1.8 V**

(V<sub>out</sub> = 1.8 V typical, V<sub>in</sub> = 2.9 V,  $T_A = -40^{\circ}C$  to +85°C, unless otherwise noted, Note 23.)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) V <sub>in</sub> = 2.9 V to 5.8 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 25°C	V <sub>out</sub>	-0.9% 1.783	1.8	+0.9% 1.817	V
Output Voltage (Accuracy) $V_{in}$ = 2.9 V to 5.8 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 0°C to +85°C	V <sub>out</sub>	-1.4% 1.774	1.8	+1.4% 1.826	V
Output Voltage (Accuracy), (Note 24) $V_{in} = 2.9 V$ to 5.8 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = -40°C to +125°C	V <sub>out</sub>	–1.5% 1.773	1.8	+1.5% 1.827	V
Line Regulation V <sub>in</sub> = 2.9 V to 12 V, I <sub>load</sub> = 0.1 mA	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation V <sub>in</sub> = 2.9 V, I <sub>load</sub> = 0.1 mA to 500 mA	Load <sub>Reg</sub>		0.04		mV/mA
Dropout Voltage (See App Note) I <sub>load</sub> = 500 mA (Notes 25, 26) I <sub>load</sub> = 300 mA (Notes 25, 26) I <sub>load</sub> = 50 mA (Notes 25, 26)	V <sub>DO</sub>		620 230 95	1130 1130 1130	mV
Peak Output Current (See Figure 16)	I <sub>pk</sub>	500	700	830	mA
Short Output Current (See Figure 16)	I <sub>sc</sub>			900	mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation I <sub>load</sub> = 500 mA (Note 25) I <sub>load</sub> = 300 mA (Note 25) I <sub>load</sub> = 50 mA I <sub>load</sub> = 0.1 mA	I <sub>GND</sub>		9.0 4.6 0.8 -	14 7.5 2.5 190	mA μA
In Dropout $V_{in} = 2.2 \text{ V}, \text{ I}_{load} = 0.1 \text{ mA}$				500	μΑ
In Shutdown S <sub>D</sub> = 0 V	I <sub>GNDsh</sub>		0.07	1.0	μΑ
Output Noise $C_{nr} = 0 nF, I_{load} = 500 mA, f = 10 Hz to 100 kHz, C_{out} = 10 \mu F$ $C_{nr} = 10 nF, I_{load} = 500 mA, f = 10 Hz to 100 kHz, C_{out} = 10 \mu F$	V <sub>noise</sub>		52 33		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	V V
$S_D$ Input Current, $V_{SD}$ = 0 V to 0.4 V or $V_{SD}$ = 2.0 V to $V_{in}$	I <sub>SD</sub>		0.07	1.0	μA
Output Current In Shutdown Mode, V <sub>out</sub> = 0 V	I <sub>OSD</sub>		0.07	1.0	μA
Reverse Bias Protection, Current Flowing from the Output Pin to GND (V <sub>in</sub> = 0 V, V <sub>out forced</sub> = 1.8 V)	I <sub>OUTR</sub>		10		μΑ

23. Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
24. For output current capability for T<sub>A</sub> < 0°C, please refer to Figure 21.</li>
25. T<sub>A</sub> must be greater than 0°C.
26. Maximum dropout voltage is limited by minimum input voltage V<sub>in</sub> = 2.9 V recommended for guaranteed operation.

## **ELECTRICAL CHARACTERISTICS - 1.5 V**

(V<sub>out</sub> = 1.5 V typical, V<sub>in</sub> = 2.9 V,  $T_A = -40^{\circ}C$  to +85°C, unless otherwise noted, Note 27.)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) V <sub>in</sub> = 2.9 V to 5.5 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 25°C	V <sub>out</sub>	-0.9% 1.486	1.5	+0.9% 1.514	V
Output Voltage (Accuracy) $V_{in}$ = 2.9 V to 5.5 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 0°C to +85°C	V <sub>out</sub>	-1.4% 1.479	1.5	+1.4% 1.521	V
Output Voltage (Accuracy), (Note 28) $V_{in}$ = 2.9 V to 5.5 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = -40°C to +125°C	V <sub>out</sub>	–1.5% 1.477	1.5	+1.5% 1.523	V
Line Regulation V <sub>in</sub> = 2.9 V to 12 V, I <sub>load</sub> = 0.1 mA	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation V <sub>in</sub> = 2.9 V, I <sub>load</sub> = 0.1 mA to 500 mA	Load <sub>Reg</sub>		0.04		mV/mA
Dropout Voltage (See App Note) I <sub>load</sub> = 500 mA (Notes 29, 30) I <sub>load</sub> = 300 mA (Notes 29, 30) I <sub>load</sub> = 50 mA (Notes 29, 30)	V <sub>DO</sub>		940 500 350	1430 1430 1430	mV
Peak Output Current (See Figure 16)	I <sub>pk</sub>	500	700	860	mA
Short Output Current (See Figure 16)	I <sub>sc</sub>			900	mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation $I_{load} = 500 \text{ mA} \text{ (Note 29)}$ $I_{load} = 300 \text{ mA} \text{ (Note 29)}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$	I <sub>GND</sub>		9.0 4.6 0.8 -	14 7.5 2.5 190	mA μA
In Dropout $V_{in} = 2.2 \text{ V}, \text{ I}_{load} = 0.1 \text{ mA}$				500	μΑ
In Shutdown $S_D = 0 V$	I <sub>GNDsh</sub>		0.07	1.0	μΑ
Output Noise C <sub>nr</sub> = 0 nF, I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF C <sub>nr</sub> = 10 nF, I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF	V <sub>noise</sub>		51 31		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	V V
$S_{D}$ Input Current, $V_{SD}$ = 0 V to 0.4 V or $V_{SD}$ = 2.0 V to $V_{in}$	I <sub>SD</sub>		0.07	1.0	μA
Output Current In Shutdown Mode, V <sub>out</sub> = 0 V	I <sub>OSD</sub>		0.07	1.0	μA
Reverse Bias Protection, Current Flowing from the Output Pin to GND (V <sub>in</sub> = 0 V, V <sub>out forced</sub> = 1.5 V)	I <sub>OUTR</sub>		10		μΑ

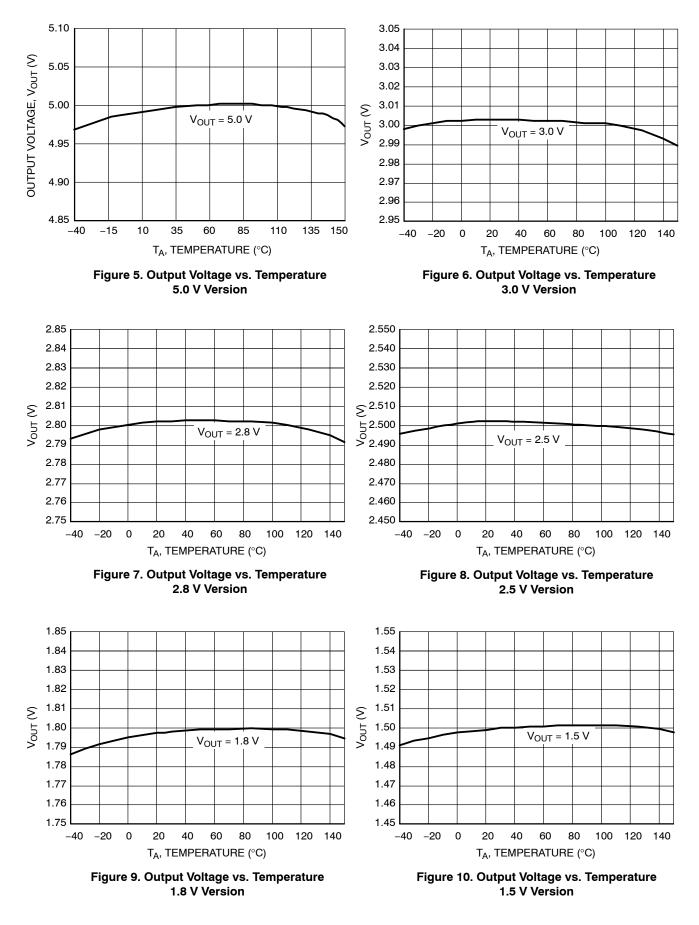
27. Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
28. For output current capability for T<sub>A</sub> < 0°C, please refer to Figure 22.</li>
29. T<sub>A</sub> must be greater than 0°C.
30. Maximum dropout voltage is limited by minimum input voltage V<sub>in</sub> = 2.9 V recommended for guaranteed operation.

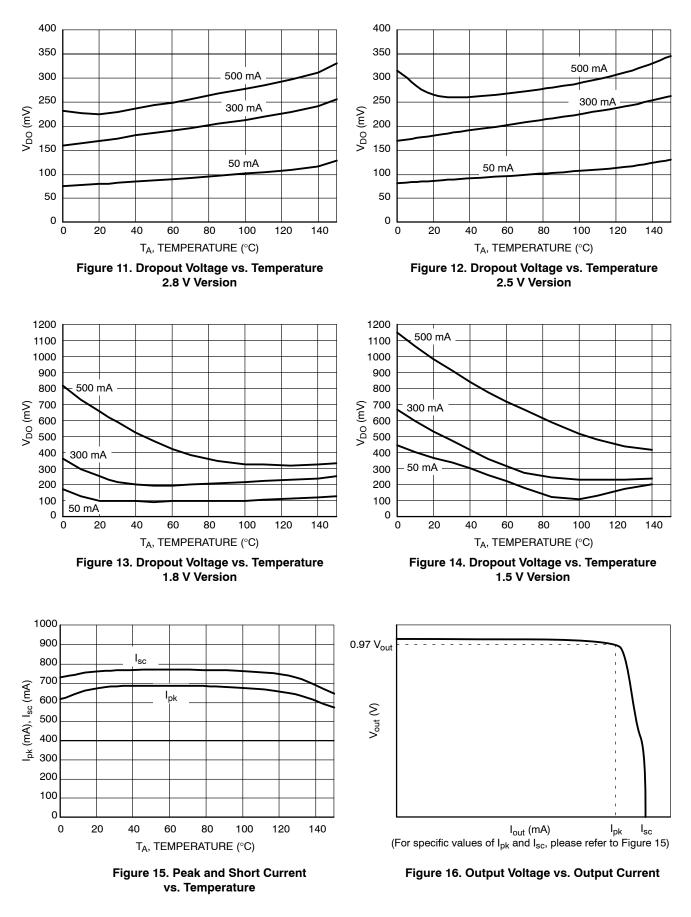
#### **ELECTRICAL CHARACTERISTICS – Adjustable**

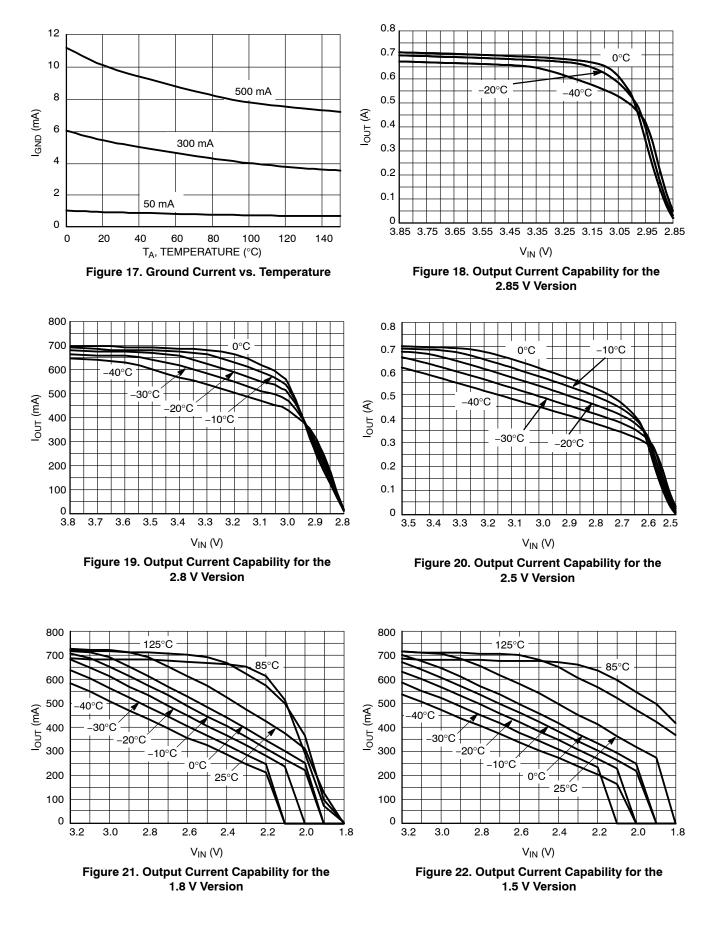
(V<sub>out</sub> = 1.25 V typical, V<sub>in</sub> = 2.9 V, T<sub>A</sub> =  $-40^{\circ}$ C to  $+85^{\circ}$ C, unless otherwise noted, Note 31)

Characteristic	Symbol	Min	Тур	Max	Unit
Reference Voltage (Accuracy) $V_{in}$ = 2.9 V to V <sub>out</sub> + 4.0 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>A</sub> = 25°C	V <sub>ref</sub>	-0.9% 1.239	1.25	+0.9% 1.261	V
Reference Voltage (Accuracy) $V_{in} = 2.9 \text{ V to } V_{out} + 4.0 \text{ V}, \text{ I}_{load} = 0.1 \text{ mA to 500 mA}, \text{ T}_{A} = 0^{\circ}\text{C to } +85^{\circ}\text{C}$	V <sub>ref</sub>	-1.4% 1.233	1.25	+1.4% 1.268	V
Reference Voltage (Accuracy) (Note 32) $V_{in} = 2.9 \text{ V to } V_{out} + 4.0 \text{ V}, I_{load} = 0.1 \text{ mA to 500 mA}, T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	V <sub>ref</sub>	-1.5% 1.231	1.25	+1.5% 1.269	V
Line Regulation V <sub>in</sub> = 2.9 V to 12 V, I <sub>load</sub> = 0.1 mA	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation V <sub>in</sub> = 2.9 V, I <sub>load</sub> = 0.1 mA to 500 mA	Load <sub>Reg</sub>		0.04		mV/mA
Dropout Voltage (See App Note), $V_{out} = 2.5$ V to 10 V $I_{load} = 500$ mA (Note 33) $I_{load} = 300$ mA $I_{load} = 50$ mA $I_{load} = 0.1$ mA	V <sub>DO</sub>			340 230 110 10	mV
Peak Output Current (Note 33) (See Figure 16)	lpk	500	700	860	mA
$ \begin{array}{llllllllllllllllllllllllllllllllllll$	I <sub>sc</sub>			900 990	mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation I <sub>load</sub> = 500 mA (Note 33) I <sub>load</sub> = 300 mA (Note 33) I <sub>load</sub> = 50 mA I <sub>load</sub> = 0.1 mA	I <sub>GND</sub>		9.0 4.6 0.8 -	14 7.5 2.5 190	mA μA
In Dropout $V_{in} = V_{out} - 0.1 \text{ V or } 2.2 \text{ V}$ (whichever is higher), $I_{load} = 0.1 \text{ mA}$			-	500	μΑ
In Shutdown $S_D = 0 V$	I <sub>GNDsh</sub>		0.07	1.0	μΑ
Output Noise $C_{nr} = 0 \text{ nF}$ , $I_{load} = 500 \text{ mA}$ , f = 10 Hz to 100 kHz, $C_{out} = 10 \mu F$ $C_{nr} = 10 \text{ nF}$ , $I_{load} = 500 \text{ mA}$ , f = 10 Hz to 100 kHz, $C_{out} = 10 \mu F$	V <sub>noise</sub>		38 26		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	V V
$S_D$ Input Current, $V_{SD}$ = 0 V to 0.4 V or $V_{SD}$ = 2.0 V to $V_{in}$ $$V_{in} \le 5.4 \ V_{in} > 5.4 \ V$	I <sub>SD</sub>		0.07	1.0 5.0	μA
Output Current In Shutdown Mode, V <sub>out</sub> = 0 V	I <sub>OSD</sub>		0.07	1.0	μA
Reverse Bias Protection, Current Flowing from the Output Pin to GND (V <sub>in</sub> = 0 V, V <sub>out forced</sub> = V <sub>out</sub> (nom) ≤ 7 V) (Note 34)	IOUTR		1.0		μA

31. Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
32. For output current capability for T<sub>A</sub> < 0°C, please refer to Figures 18 to 22.</li>
33. T<sub>A</sub> must be greater than 0°C.
34. Reverse bias protection feature valid only if V<sub>out</sub> - V<sub>in</sub> ≤ 7 V.







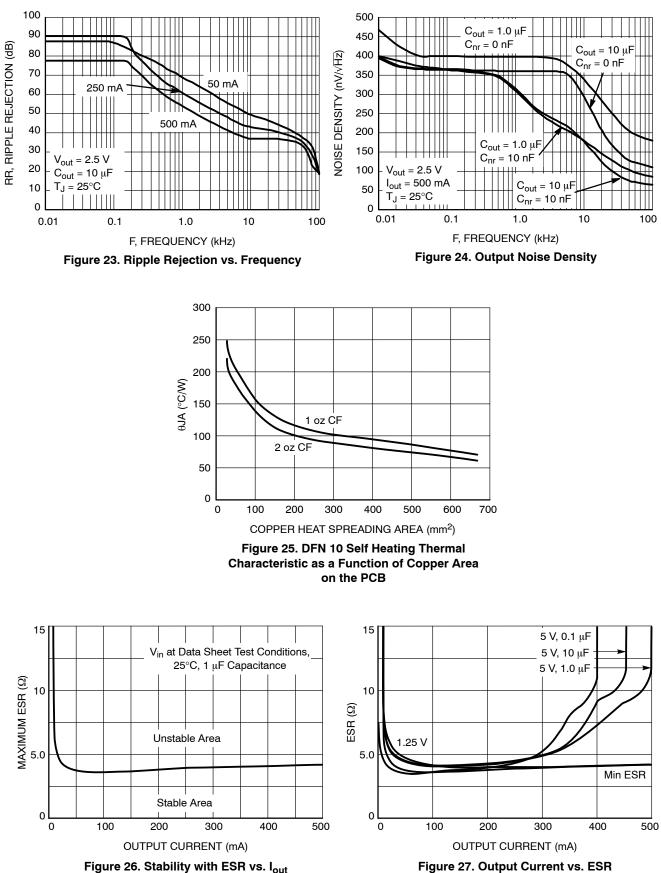


Figure 26. Stability with ESR vs. Iout

NOTE: Typical characteristics were measured with the same conditions as electrical characteristics.

## APPLICATIONS INFORMATION

## **Reverse Bias Protection**

Reverse bias is a condition caused when the input voltage goes to zero, but the output voltage is kept high either by a large output capacitor or another source in the application which feeds the output pin.

Normally in a bipolar LDO all the current will flow from the output pin to input pin through the PN junction with limited current capability and with the potential to destroy the IC.

Due to an improved architecture, the NCV8535 can withstand up to 7.0 V on the output pin with virtually no current flowing from output pin to input pin, and only negligible amount of current (tens of  $\mu$ A) flowing from the output pin to ground for infinite duration.

#### **Input Capacitor**

An input capacitor of at least 1.0  $\mu$ F, any type, is recommended to improve the transient response of the regulator and/or if the regulator is located more than a few inches from the power source. It will also reduce the circuit's sensitivity to the input line impedance at high frequencies. The capacitor should be mounted with the shortest possible track length directly across the regular's input terminals.

#### **Output Capacitor**

The NCV8535 remains stable with any type of capacitor as long as it fulfills its 1.0  $\mu$ F requirement. There are no constraints on the minimum ESR and it will remain stable up to an ESR of 5.0  $\Omega$ . Larger capacitor values will improve the noise rejection and load transient response.

#### **Noise Reduction Pin**

Output noise can be greatly reduced by connecting a 10 nF capacitor ( $C_{nr}$ ) between the noise reduction pin and ground (see Figure 1). In applications where very low noise is not required, the noise reduction pin can be left unconnected.

For the adjustable version, in addition to the 10 nF  $C_{nr}$ , a 68 pF capacitor connected in parallel with R1 (see Figure 2) is recommended to further reduce output noise and improve stability.

#### **Adjustable Operation**

The output voltage can be set by using a resistor divider as shown in Figure 2 with a range of 1.25 to 10 V. The appropriate resistor divider can be found by solving the equation below. The recommended current through the resistor divider is from 10  $\mu$ A to 100  $\mu$ A. This can be accomplished by selecting resistors in the k $\Omega$  range. As result, the I<sub>adj</sub>\*R2 becomes negligible in the equation and can be ignored.

$$V_{out} = 1.25 * \left(1 + \frac{R1}{R2}\right) + I_{adj} * R2$$
 (eq. 1)

Example:

For  $V_{out} = 2.9$  V, can use  $R_1 = 36$  k $\Omega$  and  $R_2 = 27$  k $\Omega$ .

$$1.25 * \left( 1 + \frac{36 \text{ k}\Omega}{27 \text{ k}\Omega} \right) = 2.91 \text{ V}$$
 (eq. 2)

#### **Dropout Voltage**

The voltage dropout is measured at 97% of the nominal output voltage.

#### **No-Load Regulation Considerations**

If there is no load at output of the regulator and ambient temperature is higher than  $85^{\circ}$ C leakage current flowing from input to output through pass transistor may cause increase of output voltage out of specification range up to input voltage level. To avoid this situation minimum load current of 100  $\mu$ A or higher is recommended if ambient temperature exceeds  $85^{\circ}$ C.

#### **Thermal Considerations**

Internal thermal limiting circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. This feature provides protection from a catastrophic device failure due to accidental overheating. This protection feature is not intended to be used as a substitute to heat sinking. The maximum power that can be dissipated, can be calculated with the equation below:

$$P_{D} = \frac{T_{J}(max) - T_{A}}{R_{\theta}JA}$$
 (eq. 3)

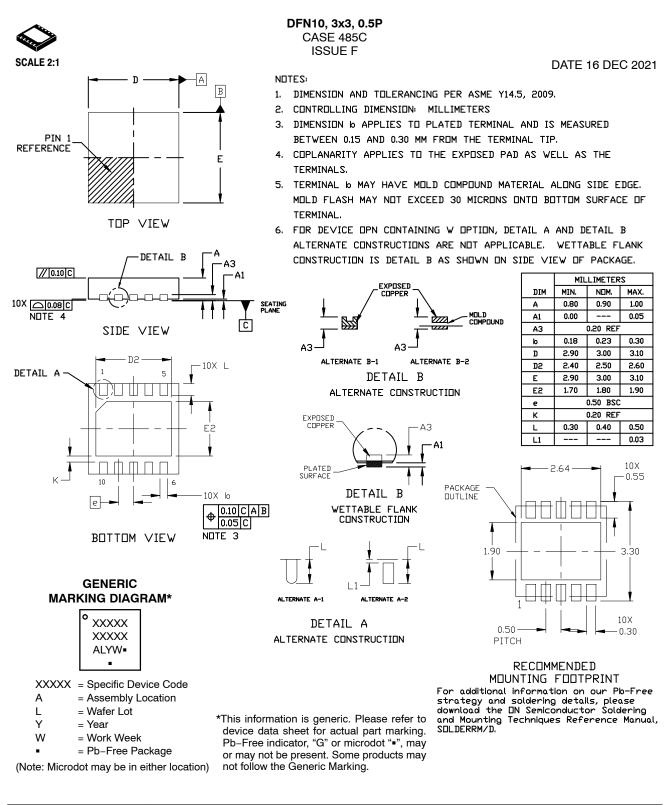
# **DEVICE ORDERING INFORMATION**

Device*	Voltage Option	Marking Code	Package	Feature	Shipping <sup>†</sup>		
NCV8535MNADJR2G	Adj.	V8535 ADJ					
NCV8535MN150R2G	1.5 V	V8535 150					
NCV8535MN180R2G	1.8 V	V8535 180					
NCV8535MN190R2G	1.9 V	V8535 190			3000 / Tape & Reel		
NCV8535MN250R2G	2.5 V	V8535 250					
NCV8535MN280R2G	2.8 V	V8535 280	DFN10 (Pb-Free)	Non-Wettable Flank			
NCV8535MN285R2G	2.85 V	V8535 285	(				
NCV8535MN300R2G	3.0 V	V8535 300					
NCV8535MN330R2G	3.3 V	V8535 330					
NCV8535MN350R2G	3.5 V	V8535 350					
NCV8535MN500R2G	5.0 V	V8535 500					
NCV8535MLADJR2G	Adj.	L8535 ADJ		Wettable Flank			
NCV8535ML180R2G	1.8 V	L8535 180	DFN10				
NCV8535ML250R2G	2.5 V	L8535 250	(Pb–Free)	SLP Process	3000 / Tape & Reel		
NCV8535ML330R2G	3.3 V	L8535 330					

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. \*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP

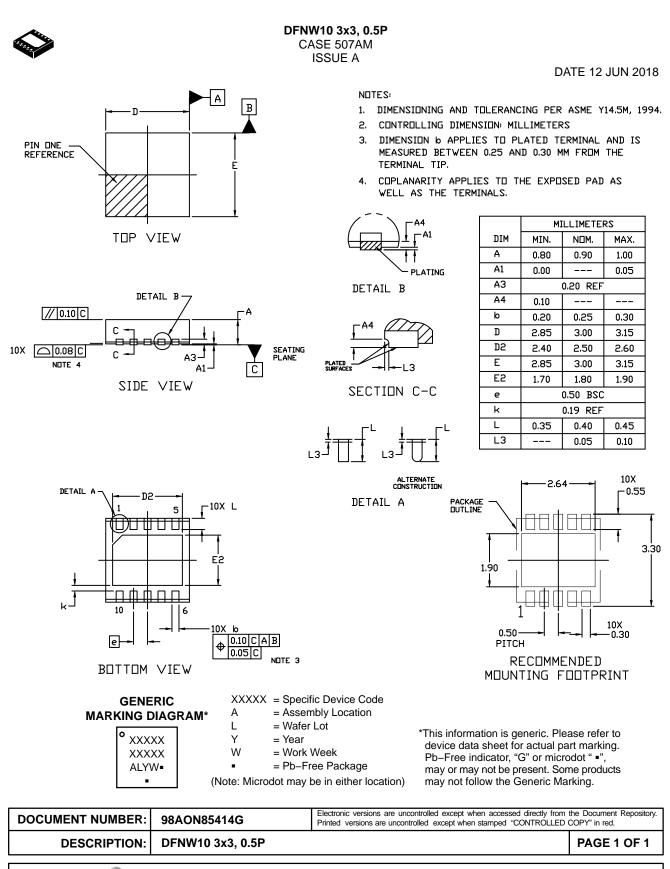
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